

CHANGE OF THE ANTIMONY ANODIZING KINETICS BY COATING THE ELECTRODE WITH A THIN FILM

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ABSTRACT

The present research work is dedicated on the processes kinetics description of the antimony anodization in potassium phosphate (K_3PO_4) aqueous solutions. The data have shown that the slope of the kinetic curves is dependent on the phosphate solution concentration. Besides, their mathematic approximation has revealed occurrence of a critical phosphate solution concentration of 0.11 mol dm^{-3} . At this concentration, the slope of the kinetic curve tends to zero. Above this critical concentration, induction periods occur during the anodization. Additional experiments were performed with thin Sb_2O_3 layers preliminarily deposited in vacuum. This approach has enabled to define the impact of such layers on the kinetic behavior during the anodization process. The results have shown that various stages of the process could be skipped. The final data analysis has confirmed the suggestion that the induction periods and voltage variations during the anodization process are caused by the formation of a thin Sb_2O_3 film, whose dielectric properties change with the film thickness increment.

Keywords: anodization of antimony, potassium phosphate, antimony oxide, vacuum thermal evaporation, induction periods.

INTRODUCTION

The anodizing of antimony in aqueous and nonaqueous solutions of acids, alkalis, and salts has been extensively studied [1 - 5]. The increased interest in the anodic behavior of antimony is due to its use in lithium-ion and sodium batteries [6 - 13] and analytical determinations [14, 15]. Induction periods are observed during anodizing under certain conditions [16] and their duration decreases with increasing current density according to a power law [17]. There are suggestions in the literature that low-impedance semiconductor layers form during induction periods in aqueous solutions of phosphoric acid [18] analogous to the induction periods

during anodizing of molybdenum [19]. According to the voltammetric and ellipsometric data, the anodic behavior is a stepwise electroformation of different antimony species, with Sb_2O_3 being the final product [20]. It was determined in reference [21] that induction periods are a common phenomenon when anodizing antimony in various electrolytes. In another study on anodizing antimony in aqueous solutions of oxalic acid [22], an increase in layer dissolution was observed with an increase in electrolyte concentration, which accounts for the occurrence of these induction periods. However, the nature of the induction periods and the “hump” that appears in some kinetic curves are not yet fully understood. This work aims to provide an experiment

that will help to understand the nature of the induction periods and the “hump” that occurs during the anodizing of antimony.

EXPERIMENTAL

Antimony electrodes (99.999 % pure) were cut into cylindrical pieces. The working surface was one of the cylinder's bases with an area of 0.8 cm^2 , which was mechanically polished using a polishing paste with grain sizes of $0.5 \text{ }\mu\text{m}$. The remaining cylinder surfaces were sealed with epoxy resin. The electrodes were anodized in a standard two-electrode cell, using a gold cathode in galvanostatic mode with a current density of 5 mA cm^{-2} and a temperature of 293 K . The continuations of the anodization processes were extended up to 330 s , in accordance either with the induction period duration or breakdown voltage achievement.

The forming electrolytes were aqueous solutions of K_3PO_4 with concentrations ranging from 0.001 to 0.12 mol dm^{-3} . The kinetic curves were sampled by acquisition of 2 data points per second, during the anodization processes. The used data acquisition device was Peak Tech 4000 digital multimeter, combined by commercial PC for data collection.

For the purpose of the present research work, another set of antimony electrodes with preliminary vacuum deposited Sb_2O_3 films was used. The oxide films were obtained by vacuum deposition from Sb_2O_3 source (with 99 % of purity, provided by Alfa Aesar, Cas No: 1309-64-4). It was vacuum-thermally evaporated by tantalum evaporator filled with quartz wool. The Sb_2O_3 film thickness varied from 7 to 100 nm , in accordance with the amounts of Sb_2O_3 loading. The film thickness values were measured using a Talystep Taylor-Hobson profiler, on a glass plate positioned near the sample. The distance between the evaporator and the substrate was 15 cm in order to keep the substrates at room temperature.

RESULTS AND DISCUSSION

The slope of the kinetic curve decreases with the increase in the electrolyte concentration, temperature, and current density reduction [23]. The dependence of the measured potential increment (dU) on the electric charge quantity (dQ) kinetic curves were acquired by galvanostatic anodization of Sb electrodes in K_3PO_4

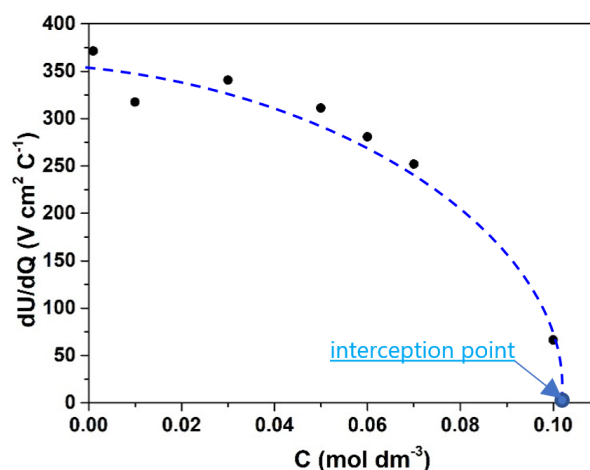


Fig. 1. Dependence of the kinetic curves slopes on the concentration of the electrolyte for anodizing of antimony in aqueous solutions of K_3PO_4 .

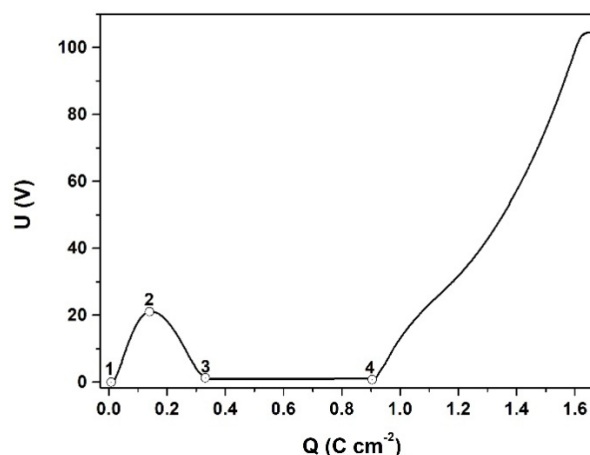


Fig. 2. Kinetic curve for anodizing of antimony (not coated with Sb_2O_3) in a 0.12 mol dm^{-3} aqueous solution of K_3PO_4 .

aqueous solutions at a constant current density of 5 mA cm^{-2} . The electrolyte concentrations were selected in a wide concentration range, as follows: 10^{-3} ; 10^{-2} ; 3×10^{-2} ; 5×10^{-2} ; 6×10^{-2} ; 7×10^{-2} and 0.1 mol dm^{-3} . The kinetic curve slope values, obtained by the respective anodizations were summarized and represented in function of the respective concentrations, as it is shown in Fig. 1.

The dependence on the electrolyte concentration, when approximated by a second-degree polynomial, crosses the abscissa at around 0.11 mol dm^{-3} , (noticed as interception point in Fig. 1) and an induction period appears immediately after this concentration (Fig. 2).

The X-axis represents the charge density, $Q = j \cdot t$, where j is the current density in mA cm^{-2} and t is the anodizing time in seconds. Besides, a “hump” is observable, where the voltage increases at the beginning of the anodizing process (section 1 - 2), reaches a maximum (point 2), then decreases back to around 0.9 V (point 3), and remains relatively constant until the end (point 4), of the induction period (section 1-4).

In cases of Sb electrodes preliminary coated by thin Sb_2O_3 layer the anodizing process kinetics is different (as shown in Figs. 3, 4, and 5). If the coating thickness is 7 nm (Fig. 3), then the hump in the kinetic curve decreases significantly, from 60 s for the uncoated electrode to only 2 to 3 s for the coated one. The hump maximum voltage also changes, decaying from above 20 V for the uncoated electrode to less than 1 V for the coated one.

This hump completely disappears at higher Sb_2O_3 layer thickness, as it is demonstrated in Fig. 4.

The experiments have revealed that the thicker Sb_2O_3 layers result in shortening of the induction periods during the anodization of the respective samples, as is shown in Fig. 5.

At higher thicknesses, the induction period may even become negligible, as depicted in Fig. 6.

The change in the kinetics of anodizing may be attributed to variations in the properties of the resulting film. A correlation between the band gap width and film thickness has been established for some materials [24 - 27]. A reduction in thickness to less than 10 nm can lead to an increase in the band gap due to quantum confinement and amorphous effects [24]. This phenomenon of band gap width reduction with increasing layer thickness has been observed for anodic films on zinc [28]. Additionally, a dependence of the kinetic curve slope and the layer band gap width on electrolyte concentration was found [29].

At the start of anodizing, when the film thickness grows from zero to a certain value, the layer's specific resistance is high due to the large band gap, causing an increase in the formation voltage. Upon reaching a certain thickness, the band gap width starts to decrease, leading to a reduction in specific resistance and voltage drop, resulting in a hump on the kinetic curve. At this stage (point 3 in Fig. 2), the electronic current is very high, the ionic current is very low, the film growth and dissolution are almost equal, and the film thickness increases very slowly. After point 4 (Fig. 2), the

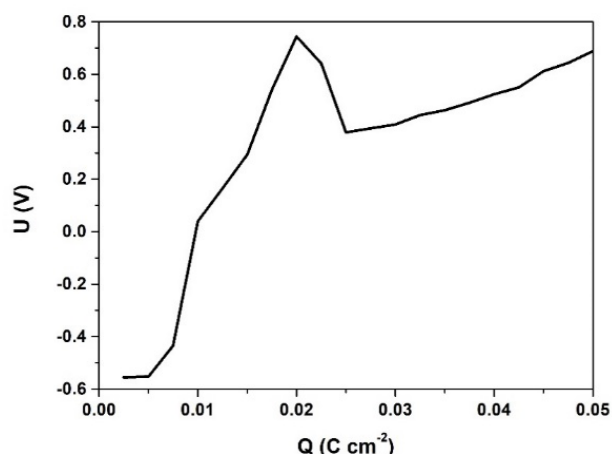


Fig. 3. Kinetic curve for anodizing of antimony, with preliminary deposited Sb_2O_3 layers with 7 nm thickness in 0.12 mol dm^{-3} aqueous solution of K_3PO_4 .

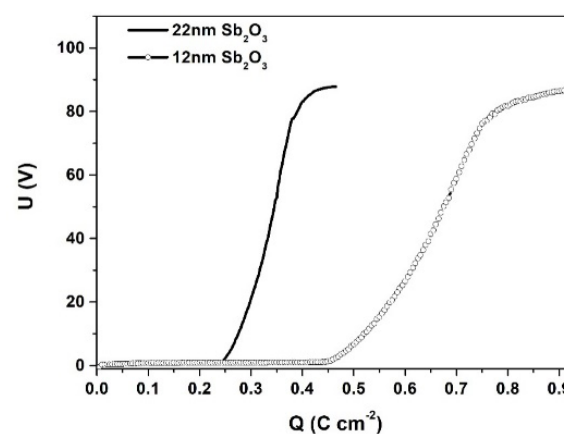


Fig. 4. Kinetic curves for anodizing of antimony with preliminary deposited Sb_2O_3 layers with 12 and 22 nm thickness in 0.12 mol dm^{-3} K_3PO_4 aqueous solution.

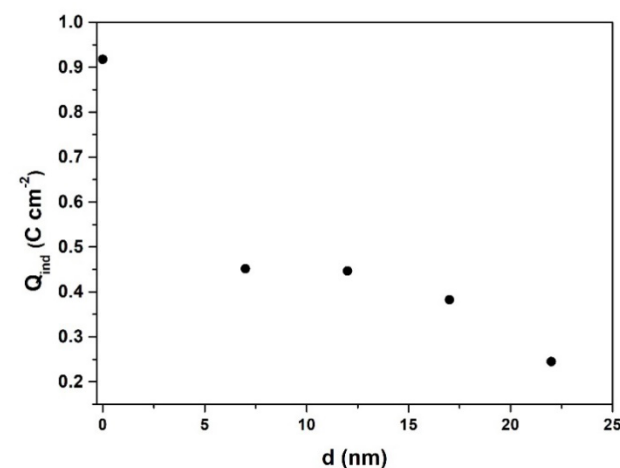


Fig. 5. Dependence of the charge density passed till the end of the induction period Q_{ind} on the thickness of the Sb_2O_3 coating for anodizing in a 0.12 mol dm^{-3} aqueous solution of K_3PO_4 .

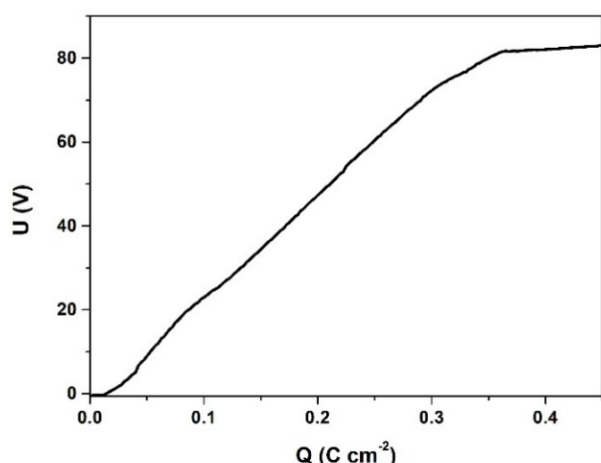


Fig. 6. Kinetic curve for anodizing of antimony preliminary coated with a 100 nm thick Sb_2O_3 layer in a 0.12 mol dm^{-3} aqueous solutions of K_3PO_4 .

mechanism could be as proposed in [22]. Dissolution products block a portion of the electrode surface, causing an increase in current density through the free surface. When it reaches a certain value, the induction period ends. At this point, the voltage becomes grow notably, due to the thickening of the already formed oxide layer.

The preliminary vacuum deposited Sb_2O_3 thin (near 7 nm) layers change the kinetic curve shapes, since the kinetic curves initiations in these cases coincide with the end of the hump areas (i.e. near point 3 in Fig. 2).

In the cases of preliminary vacuum deposited Sb_2O_3 layers with thicknesses between 12 and 22 nm, the respective anodization kinetic curves initiations correspond the interval enclosed between points 3 and 4 (Fig. 2), so that for thicker coatings, the kinetic curve initiations are closer to point 4 (Fig. 2). Consequently, the anodization kinetic curve could start even after point 4, when the preliminary Sb_2O_3 layer is sufficiently thick. However, such cases were not observed during the experiments. The probable reason is the strong non-stoichiometry and instability of the vacuum-thermally deposited Sb_2O_3 layers [30, 31]. As a result, the kinetic curves for the anodizing of antimony electrodes coated with a Sb_2O_3 layer always begin from zero voltage even at high thickness values (Fig. 6). These effects become weaker at higher current densities and eventually, the induction period could even disappear at rather high current densities.

CONCLUSIONS

The preliminary Sb_2O_3 layer vacuum-thermal deposition of the Sb electrodes significantly affects the shape of the kinetic curves, acquired during the anodization in K_3PO_4 aqueous solutions. The thicker preliminary deposited Sb_2O_3 layers result in shortening of the initial induction periods. These periods could completely disappear, when the Sb_2O_3 layers are sufficiently thick. This phenomenon, along with the dependence of the kinetic curve slope and the layer band gap width on electrolyte concentration, suggests that the alteration in the dielectric properties of the thin film formed on the electrode surface plays much more significant role in the kinetics of anodizing than previously believed.

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